



# Product Change Notification Number: SC120701

Notification Date\*: March 6, 2012

Title: 8-Mbit Se (WLCSP) Packa	rial Flash (AT25DF081, 1.65V to 1.95V) Proge Offering	ocess Geometry Shrink and I	Discontinuance of 11-Ball dBGA			
Product Identifi	cation:					
All package optic	ons of the Industrial Temperature Grade (-4	40°C to +85°C) AT25DF081				
Replacement pa	rts numbers are shown in Table 1.					
Reason for Change:	Material / Composition	Design / Firmware	Manufacturing Location			
	Processing / Manufacturing		Quality / Reliability			
Change Descri	otion:					
Atmel has performed a geometric process shrink of the AT25DF081 Serial Flash (8-Mbit density, 1,65V to 1.95V) from 130nm to 110nm. The catalog part number AT25 <u><i>DF</i></u> 081 will be replaced by AT25 <u><i>DL</i></u> 081.						
The new devices are pin-to-pin and backward compatible with the current 25DF081 devices.						
The 11-ball dBGA (WLCSP) is being replaced with an 8-ball dBGA (WLCSP), since the 8-ball utilizes the same active ball matrix layout (the center 8 balls) as the 11-ball package. Please contact Atmel for the Package Outline Drawings for the 11-ball and 8-ball dBGA packages.						
Table 1 below cr	oss references the current and new part nu	umbers.				
	Table 1					
	Current Part Number	New Part Number				
	AT25DF081-MHN-T	AT25DL081-MHN-T				
	AT25DF081-MHN-Y	AT25DL081-MHN-Y				
	AT25DF081-SSHN-B	AT25DL081-SSHN-B				
	AT25DF081-SSHN-T	AT25DL081-SSHN-T				
	AT25DF081-UUN-T	AT25DL081-UUN-T				
Attachment A provides a basic key feature comparison between the current and new devices.						
	Datasheets for both the old	d and new devices can be fo	ound @			
http://www.atmel.com/products/memories/sflash/default.aspx?tab=documents&Asset_Type=010 Datasheet						
< <u>CLICK OR SCAN HERE&gt;</u>						
www.atmel.com						

#### Identification Method to Distinguish Change:

New catalog part numbers will be identifiable by the root part number code (AT25<u>*DF*</u>081 changes to AT25<u>*DL*</u>081). Please refer to Table 1 for catalog part number changes.

Qualification Data:	🛛 Available	Will be available (mm/dd/yr):	Not Applicable
Samples:	🛛 Available	☐ Will be available (mm/dd/yr):	Not Applicable

Quantifiable Impact on Quality & Reliability: The new devices are form, fit and functionally equivalent to the current devices, which meet all datasheet specifications.

## Forecasted Availability Date: Now

Last Time Buy Date: August 31, 2012

Last Ship Date: February 28, 2013

\*All orders placed after the notification date are non-cancellable and non-returnable (NCNR).

### Atmel Contact: pcnadm@atmel.com

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Company:
Name:
Title:
Date:
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Location:
Comments:

# **Attachment A**

Key Feature Set Comparison					
	AT25DF081	AT25DL081			
VCC Range	1.65V to 1.95V	1.65V to 1.95V			
Maximum CLK Frequency	66MHz SPI	85Mhz SPI			
		100Mhz RapidS™			
Interface Options	SPI	SPI, RapidS™, Dual I/O			
OTP Protection Register (e-S/N)	N/A	128Byte = (64Byte factory + 64Byte User)			
Flexible Erase Architecture	– Uniform 4KB block erase	<ul> <li>– Uniform 4KB block erase</li> </ul>			
	<ul> <li>– Uniform 32KB block erase</li> </ul>	<ul> <li>– Uniform 32KB block erase</li> </ul>			
	<ul> <li>– Uniform 64KB block erase</li> </ul>	<ul> <li>– Uniform 64KB block erase</li> </ul>			
	– Full chip erase	– Full chip erase			
Individual Sector Protection	<ul> <li>– 16 sectors of 64KB each</li> </ul>	<ul> <li>– 16 sectors of 64KB each</li> </ul>			
Sector Lockdown	N/A	<ul> <li>Any combination of 64KB sectors permanently read-only</li> </ul>			
Fast Program Erase Times	– 1.0ms typical page program (256 bytes)	<ul> <li>– 1.0ms typical page program (256 bytes)</li> </ul>			
	<ul> <li>– 50ms typical 4KB block erase time</li> </ul>	– 50ms typical 4KB block erase time			
	<ul> <li>– 350ms typical 32KB block erase time</li> </ul>	<ul> <li>– 250ms typical 32KB block erase time</li> </ul>			
	<ul> <li>– 600ms typical 64KB block erase time</li> </ul>	– 550ms typical 64KB block erase time			
Program Erase Suspend Resume	N/A	YES			
Low Power Operation	<ul> <li>– 7mA active read current (@ 20MHz)</li> </ul>	– 10mA active read current (@ 20MHz)			
	– 8μA deep power-down current (typical)	– 8µA deep power-down current (typical)			
Software RESET	N/A	YES			
JEDEC Device / Manufacturer ID	1Fh	1F			
JEDEC Device ID (Byte 1)	45h	45h			
JEDEC Device ID (Byte 2)	02h	02H			
JEDEC Extended Device Information	00h	01h			
	N/A	00h			
Endurance	100K cycles	100K Cycles			
Data Retention	20years	20Years			
Operating Temperature Range	-40°C to +85°C	-40°C to +85°C			
Package Options	– 8-lead SOIC (0.150" Wide Body)	– 8-lead SOIC (0.150" Wide Body)			
	– 8-pad ultra thin DFN (5 x 6 x 0.6mm)	– 8-pad ultra thin DFN (5 x 6 x 0.6mm)			
	– 11-ball dBGA (WLCSP)	– 8-ball dBGA (WLCSP)			
This is a basis comparison of kow	features . Diasso refer the product datashe				